High-Speed, Low r$_{ON}$, 1.8-V/2.5-V/3.3-V/5-V, SPST Analog Switch
(1-Bit Bus Switch)

FEATURES

- SC-70 5-Lead Package
- 5-Ω Switch Connection Between Two Ports
- Minimal Propagation Delay Through The Switch
- Low I$_{CC}$
- Zero Bounce In Flow-Through Mode
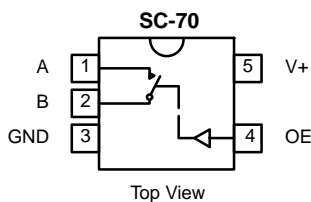- Control Inputs Compatible with TTL Level

DESCRIPTION

The DG2303 is a high-speed, 1-bit, low power, TTL-compatible bus switch. Using sub-micron CMOS technology, DG2303 achieves low on-resistance and negligible propagation delay.

The DG2303 consist of a bi-directional input/output pins A and B. When the output enable (OE) is low, the input/output pins are connected. When the OE is high, the switch is open and a high-impedance state exists between input/output pins A and B.

FUNCTIONAL BLOCK DIAGRAM AND PIN CONFIGURATION

SC-70

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        _____
A   [1]            [5]  V+
B   [2]
GND [3]            [4]  OE
        _____
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Top View

Device Marking: E6

TRUTH TABLE

OE	B	Function
L	HiZ State	Disconnect
H	A	Connect

ORDERING INFORMATION

Temp Range	Package	Part Number
-40 to 85°C	SC70-5	DG2303DL

DG2303

Vishay Siliconix   *New Product*

VISHAY

ABSOLUTE MAXIMUM RATINGS

Reference to GND
V+ . . . . -0.3 to +6 V
OE, A, B[a] . . . . -0.3 to (V+ + 0.3 V)
Continuous Current (Any terminal) . . . . $\pm$ 50 mA
Peak Current . . . . $\pm$ 200 mA
(Pulsed at 1 ms, 10% duty cycle)
Storage Temperature (D Suffix) . . . . -65 to 150°C

Power Dissipation (Packages)[b]
5-Pin SC70[c] . . . . 250 mW

Notes:
a. Signals on A, or B or OE exceeding V+ will be clamped by internal diodes. Limit forward diode current to maximum current ratings.
b. All leads welded or soldered to PC Board.
c. Derate 3.1 mW/°C above 70°C

SPECIFICATIONS (V+ = 5.0 V)

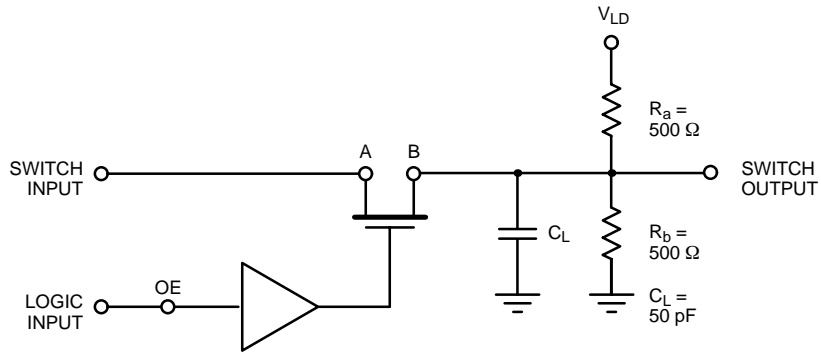| Parameter	Symbol	Test Conditions Otherwise Unless Specified V+ = 1.65 V to 5.5 V, V_{IN} = V_{IH} or V_{IL}[e]	Temp[a]	Min[b]	Typ[c]	Max[b]	Unit
DC Characteristics							
On-Resistance	r_{ON}	V+ = 1.8 V, V_A = 0 V, I_B = 4 mA	Full			28.0	Ω
		V+ = 1.8 V, V_A = 1.8 V, I_B = 4 mA	Full			60.0	
		V+ = 2.3 V, V_A = 0 V, I_B = 8 mA	Full			12.0	
		V+ = 2.3 V, V_A = 2.3 V, I_B = 8 mA	Full			30.0	
		V+ = 3.0 V, V_A = 0 V, I_B = 24 mA	Full			9.0	
		V+ = 3.0 V, V_A = 3.0 V, I_B = 24 mA	Full			20.0	
		V+ = 4.5 V, V_A = 0 V, I_B = 30 mA	Full			7.0	
		V+ = 4.5 V, V_A = 2.4 V, I_B = 15 mA	Full			12.0	
		V+ = 4.5 V, V_A = 4.5 V, I_B = 30 mA	Full			15.0	
r_{ON} Flatness[d]	r_{ON} Flatness	V+ = 1.8 V, V_A = 0 V to V+, I_B = 4 mA	Full		125		
		V+ = 2.5 V, V_A = 0 V to V+, I_B = 8 mA	Full		28		
		V+ = 3.3 V, V_A = 0 V to V+, I_B = 24 mA	Full		12		
		V+ = 5.0 V, V_A = 0 V to V+, I_B = 30 mA	Full		6		
Switch Off Leakage Current	$I_{(off)}$	V+ = 5.5 V, V_A = 1 V/4.5 V, V_B = 4.5 V/1 V	Full	-10		10	μA
Switchl-On Leakage Current	$I_{(on)}$	V+ = 5.5 V, V_A = V_B = 1 V/4.5 V	Full	-10		10	
Input High Voltage	V_{IH}	V+ = 1.65 V to 1.95 V	Full	1.35			V
		V+ = 2.3 V to 2.7 V	Full	1.6			
		V+ = 3.0 V to 3.6 V	Full	2.0			
		V+ = 4.5 V to 5.5 V	Full	2.4			
Input Low Voltage	V_{IL}	V+ = 1.65 V to 1.95 V	Full			0.4	
		V+ = 2.3 V to 2.7 V	Full			0.4	
		V+ = 3.0 V to 3.6 V	Full			0.6	
		V+ = 4.5 V to 5.5 V	Full			0.8	
Input Current	I_{IL} or I_{IH}	V_{OE} = 0 or V+	Full	-1		1	μA
Dynamic Characteristics							
Prop Delay Bus-to-Bus[f]	t_{PHL}, t_{PLH}	V_{LD} = Open, V= 1.65 V to 1.95 V, (Figure 1 and 2)	Full			5	ns
		V_{LD} = Open, V= 2.3 V to 2.7 V, (Figure 1 and 2)	Full			2	
		V_{LD} = Open, V= 3.0 V to 3.6 V, (Figure 1 and 2)	Full			1	
		V_{LD} = Open, V= 4.5 V to 5.5 V, (Figure 1 and 2)	Full			1	

SPECIFICATIONS (V+ = 5.0 V)

Parameter	Symbol	Test Conditions Otherwise Unless Specified V+ = 1.65 V to 5.5 V, V_{IN} = V_{IH} or V_{IL}[e]	Temp[a]	Limits -40 to 85°C Min[b]	Typ[c]	Max[b]	Unit
Dynamic Characteristics							
Output Enable Time[d]	t_{PZL}	V_{LD} = 2 x V+, V+ = 1.65 V to 1.95 V (Figure 1 and 2)	Full		4.2		ns
		V_{LD} = 2 x V+, V+ = 2.3 V to 2.7 V (Figure 1 and 2)	Full		3.3		
		V_{LD} = 2 x V+, V+ = 3.0 V to 3.6 V (Figure 1 and 2)	Full		2.6		
		V_{LD} = 2 x V+, V+ = 4.5 V to 5.5 V (Figure 1 and 2)	Full		1.8		
	t_{PZH}	V_{LD} = 0 V, V+ = 1.65 V to 1.95 V (Figure 1 and 2)	Full		4.4		
		V_{LD} = 0 V, V+ = 2.3 V to 2.7 V (Figure 1 and 2)	Full		3.3		
		V_{LD} = 0 V, V+ = 3.0 V to 3.6 V (Figure 1 and 2)	Full		2.7		
		V_{LD} = 0 V, V+ = 4.5 V to 5.5 V (Figure 1 and 2)	Full		2.0		
Output Disable Time[d]	t_{PLZ}	V_{LD} = 2 x V+, V+ = 1.65 V to 1.95 V (Figure 1 and 2)	Full		14.3		ns
		V_{LD} = 2 x V+, V+ = 2.3 V to 2.7 V (Figure 1 and 2)	Full		10.5		
		V_{LD} = 2 x V+, V+ = 3.0 V to 3.6 V (Figure 1 and 2)	Full		8.6		
		V_{LD} = 2 x V+, V+ = 4.5 V to 5.5 V (Figure 1 and 2)	Full		7.4		
	t_{PHZ}	V_{LD} = 0 V, V+ = 1.65 V to 1.95 V (Figure 1 and 2)	Full		10.7		
		V_{LD} = 0 V, V+ = 2.3 V to 2.7 V (Figure 1 and 2)	Full		9.6		
		V_{LD} = 0 V, V+ = 3.0 V to 3.6 V (Figure 1 and 2)	Full		8.7		
		V_{LD} = 0 V, V+ = 4.5 V to 5.5 V (Figure 1 and 2)	Full		7.5		
Charge Injection[d]	Q_{INJ}	C_L = 1 nF, V_{GEN} = 0 V, R_{GEN} = 0 Ω, (Figure 3)	Room		0.5		pC
Off Isolation[d]	OIRR	R_L = 50 Ω, C_L = 5 pF, f = 10 MHz	Room		-50		dB
Insertion Loss[d]	Loss	R_L = 50 Ω	Room		>200		MHz
Input Capacitance[d]	C_{in}		Room		4		pF
Channel-Off Capacitance[d]	$C_{(off)}$	V_{OE} = 0 or V+, f = 1 MHz	Room		9		
Channel-On Capacitance[d]	C_{ON}		Room		20		
Power Supply							
Power Supply Range	V+			1.65		5.5	V
Power Supply Current	I+	V_{OE} = 0 or V+				1.0	µA

Notes:

a. Room = 25°C, Full = as determined by the operating suffix.
b. The algebraic convention whereby the most negative value is a minimum and the most positive a maximum, is used in this data sheet.
c. Typical values are for design aid only, not guaranteed nor subject to production testing.
d. Guarantee by design, nor subjected to production test.
e. V_{IN} = input voltage to perform proper function.
f. Guaranteed by design and not production tested. The bus switch propagation delay is a function of the RC time constant contributed by the on-resistance and the specified load capacitance with an ideal voltage source (zero output impedance) driving the switch.

AC LOADING AND WAVEFORMS

Input driven by 50-Ω source terminated in 50 Ω

C_L includes load and stray capacitance

Input PRR = 1.0 MHz, t_W = 50 ns
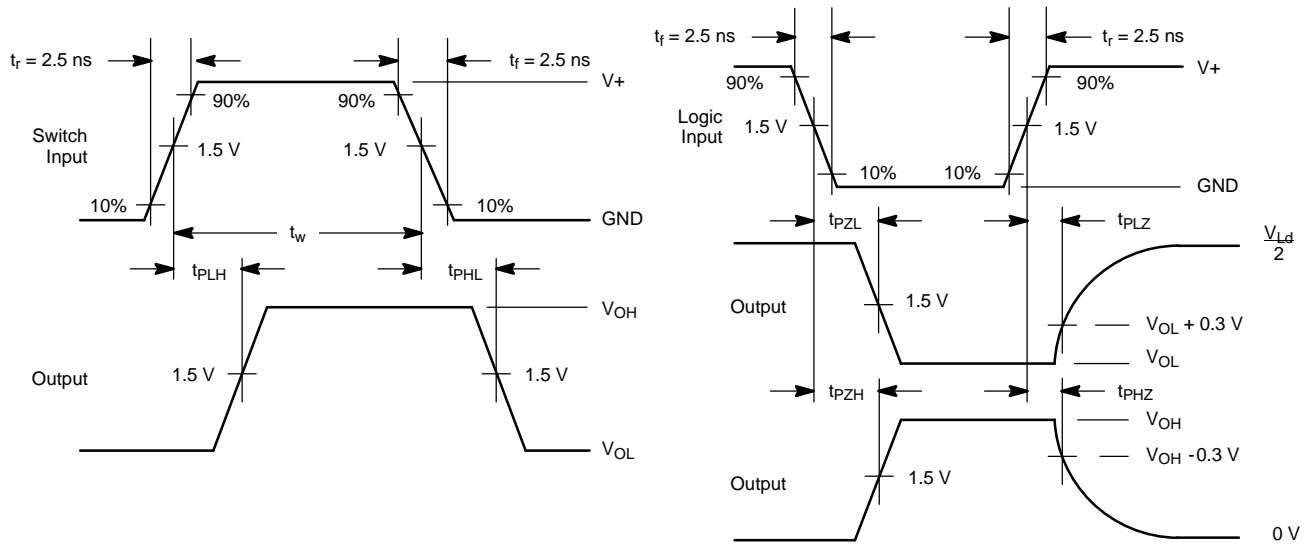
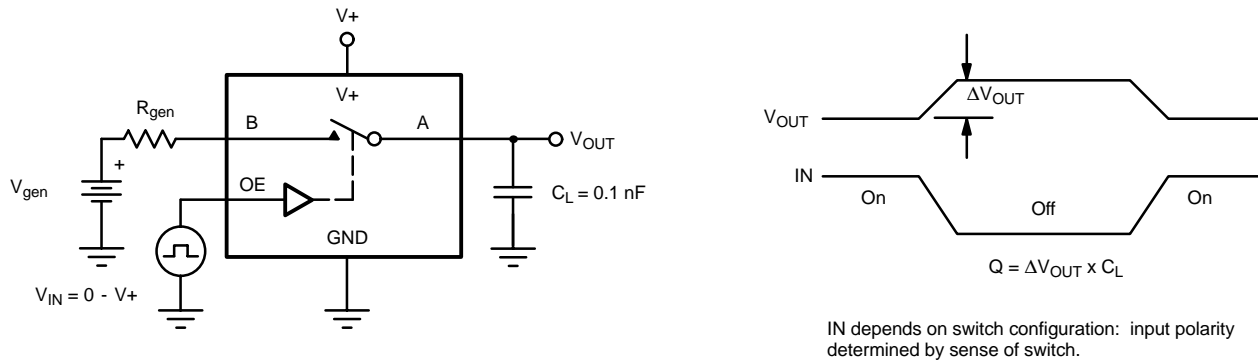**Figure 1.** AC Test Circuit

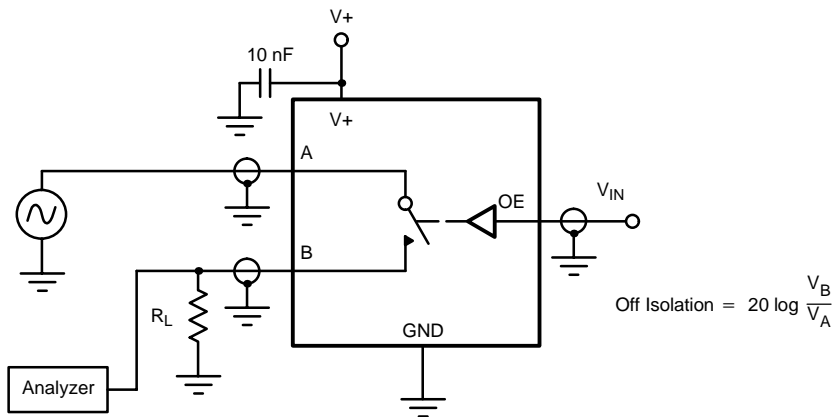**Figure 2.** AC Waveforms

TEST CIRCUITS

Figure 3. Charge Injection

$$Q = \Delta V_{OUT} \times C_L$$

IN depends on switch configuration: input polarity determined by sense of switch.

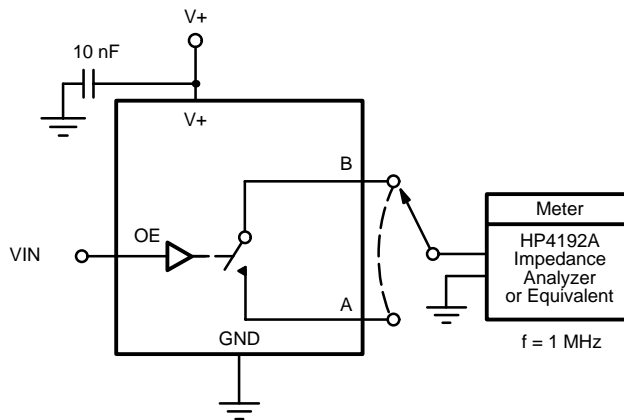
Figure 4. Off-Isolation

$$\text{Off Isolation} = 20 \log \frac{V_B}{V_A}$$

FIGURE 5. Channel Off/On Capacitance